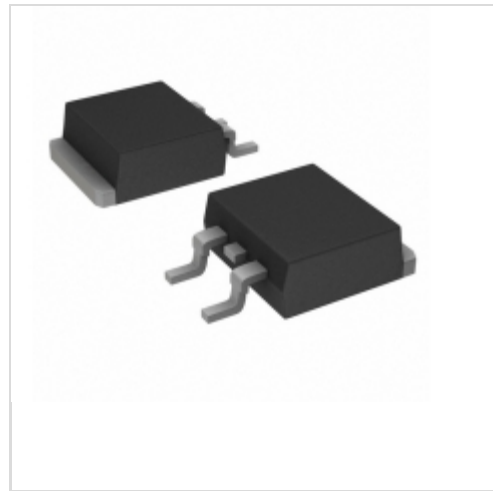


UGB5JT-E3/45

Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 600V 5A TO263AB

Lead free / RoHS Compliant

Discrete Semiconductor Products

[UGB5JT-E3/45.pdf](#)
Out Stock
0 pcs

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

Images are for reference only.

See Product Specifications for product details.

If you are interested to buy UGB5JT-E3/45,Just Email us.

Sales@zeanoit.com

our sales team will reply you within 24 hours

Shopping Process
1
Confirm the product
2
submit the order
3
payment
4
wait for delivery
5
receive the goods
Specifications

Voltage - Forward (Vf) (Max) @ If:	1.75V @ 5A
Voltage - DC Reverse (Vr) (Max):	600V
Supplier Device Package:	TO-263AB
Speed:	Fast Recovery = 200mA (Io)
Series:	-
Reverse Recovery Time (trr):	50ns
Packaging:	Tube
Package / Case:	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Operating Temperature - Junction:	-55°C ~ 150°C
Mounting Type:	Surface Mount
Diode Type:	Standard
Current - Reverse Leakage @ Vr:	30µA @ 600V
Current - Average Rectified (Io):	5A
Capacitance @ Vr, F:	-

Related products

UGB5JT-E3/81

DIODE GEN PURP 600V 5A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


UGB5HT-E3/81

DIODE GEN PURP 500V 5A TO263AB

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UGB5JT-E3/45

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RFQ


UGB5HT-E3/45

DIODE GEN PURP 500V 5A TO263AB

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RFQ


UGB5JT
[N/A](#)

RFQ


UGB5HT-E3/81

DIODE GEN PURP 500V 5A TO263AB

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RFQ


UGB3132AD

IC MOD DIODE 1PHASE BRIDGE UGB1

[IXYS](#)

RFQ


UGB6124AG

IC MOD DIODE 1PHASE BRIDGE UGB1

[IXYS](#)

RFQ


UGB8AT-E3/81

DIODE GEN PURP 50V 8A TO263AB

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RFQ


UGB5JT-E3/81

DIODE GEN PURP 600V 5A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ

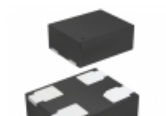
Guess You May Looking For

SIT1602BI-13-33E-60.000000D

-40 TO 85C, 2520, 50PPM, 3.3V, 6

[SITIME](#)

RFQ


SIT1602BI-71-25E-74.175824D

-40 TO 85C, 2016, 20PPM, 2.5V, 7

[SITIME](#)

RFQ


SIT1602BI-22-18S-24.000000D

-40 TO 85C, 3225, 25PPM, 1.8V, 2

[SITIME](#)

RFQ


SIT8008AIL71-33S-20.000000D

OSC MEMS 20.0000MHZ LVCMOS SMD

[SITIME](#)

RFQ


SIT1602BC-32-25E-4.000000Y

-20 TO 70C, 5032, 25PPM, 2.5V, 4

[SITIME](#)

RFQ


SIT1602BI-21-30E-38.400000D

-40 TO 85C, 3225, 20PPM, 3.0V, 3

[SITIME](#)

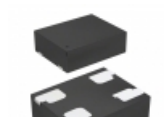
RFQ


SIT2001BC-S2-33E-48.000000G

OSC XO 48.0000MHZ H/LV-CMOS SMD

[SITIME](#)

RFQ


SIT8008BI-13-33E-25.000000G

OSC MEMS 25.0000MHZ LVCMOS SMD

[SITIME](#)

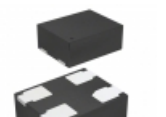
RFQ


SIT1602BC-13-25E-10.000000G

-20 TO 70C, 2520, 50PPM, 2.5V, 1

[SITIME](#)

RFQ


SIT1602BC-72-33N-4.096000G

-20 TO 70C, 2016, 25PPM, 3.3V, 4

[SITIME](#)

RFQ